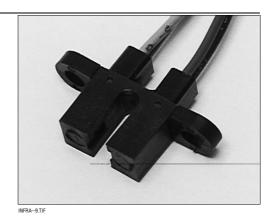
### **Transmissive Sensor**

#### **FEATURES**

- Choice of phototransistor or photodarlington output
- 0.060 in.(1.52 mm)dia. detector aperture
- 0.125 in.(3.18 mm) slot width
- 18.0 in.(457 mm) min. 22 AWG UL 1429 wire leads



#### DESCRIPTION

The HOA1881 series consists of an infrared emitting diode facing an NPN silicon phototransistor (HOA1881-011, - 012) or photodarlington (HOA1881-013) encased in a black thermoplastic housing. Detector switching takes place whenever an opaque object passes through the slot between emitter and detector. The lead wires of minimum length 18.0 in.(457 mm) provide alternate electrical connection when PC board mounting is not possible. The HOA1881 series employs plastic molded components. For additional component information see SEP8506, SDP8406, and SDP8106.

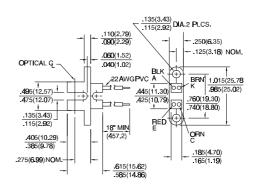
Housing material is nylon. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

Wire color code and functions are:

Black - IRED Anode
Orange - Detector Collector
Brown - IRED Cathode
Red - Detector Emitter

#### OUTLINE DIMENSIONS in inches (mm)

Tolerance 3 plc decimals  $\pm 0.010(0.25)$ 2 plc decimals  $\pm 0.020(0.51)$ 



DIM\_052.cdr



### **Transmissive Sensor**

### ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER						
Forward Voltage	VF			1.6	V	I <sub>F</sub> =20 mA
Reverse Leakage Current	l <sub>R</sub>			10	μΑ	V <sub>R</sub> =3 V
DETECTOR Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>				V	I <sub>C</sub> =100 μΑ
HOA1881-011, -012	A (BH)CEO	30			V	10-100 μΑ
HOA1881-013		15				
Emitter-Collector Breakdown Voltage	V <sub>(BR)ECO</sub>	5.0			V	I <sub>E</sub> =100 μA
Collector Dark Current	ICEO				nA	V <sub>CE</sub> =10 V
HOA1881-011, -012				100		I <sub>F</sub> =0
HOA1881-013				250		
COUPLED CHARACTERISTICS						
On-State Collector Current	Ic(on)				mA	V <sub>CE</sub> =5 V
HOA1881-011		0.3				I <sub>F</sub> =20 mA
HOA1881-012		1.8				
HOA1881-013		4.0				
Collector-Emitter Saturation Voltage	VCE(SAT)				V	l <sub>F</sub> =20 mA
HOA1881-011				0.4		lc=40 μA
HOA1881-012				0.4		Ic=230 μA
HOA1881-013				1.1		Ic=500 μA
Rise And Fall Time	t <sub>r</sub> , t <sub>f</sub>				μs	Vcc=5 V, lc=1 mA
HOA1881-011, -012			15			$R_L=1000 \Omega$
HOA1881-013			75			$R_L=100 \Omega$

#### **ABSOLUTE MAXIMUM RATINGS**

(25°C Free-Air Temperature unless otherwise noted)

Operating Temperature Range -40°C to 85°C

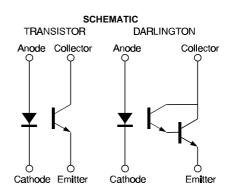
Storage Temperature Range -40°C to 85°C

Soldering Temperature (5 sec) 240°C

IR EMITTER

Power Dissipation 100 mW <sup>(1)</sup>
Reverse Voltage 3 V
Continuous Forward Current 50 mA

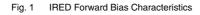
DETECTORTRANS.DARLINGTONCollector-Emitter Voltage30 V15 VEmitter-Collector Voltage5 V5 VPower Dissipation100 mW (¹)100 mW (¹)Collector DC Current30 mA30 mA

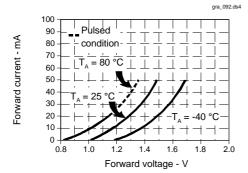


Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

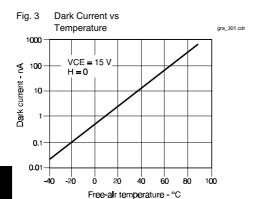
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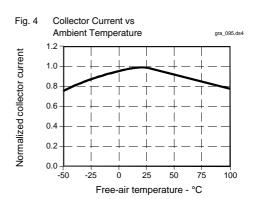
### **Transmissive Sensor**





Non-Saturated Switching Time vs Load Resistance 1000 ▤◾▦▦ Response time - µs 100 Photodarlington = = = = Phototransistor ŦI#I# 10 100 1000 10000 Load resistance - Ohms





All Performance Curves Show Typical Values

**Transmissive Sensor**